NSN 5962-01-481-3630

Memory Microcircuit - Page 1 of 1



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Maximum Power Dissipation Rating:
550.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Sentinel radar system
Features Provided:
Monolithic and ultraviolet erasable
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Product Name:
Microcircuits, memory, digital, cmos, 2k x 8 uv erasable, prom, monolithic silicon
Voltage Rating And Type Per Characteristic:
4.5 volts power source and 5.0 volts power source
Time Rating Per Chacteristic:
25.00 nanoseconds af output megawatts
Memory Device Type:
Prom
Test Data Document:
$96906 \hbox{-mil-std-}883 \ standard \ (includes \ industry \ or \ association \ standards, \ individual \ manufactureer \ standards, \ etc.).$
Terminal Type And Quantity:
24 printed circuit
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:
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